



74AHCT1G126Q

SINGLE BUFFER GATE WITH 3-STATE OUTPUT

### Description

The 74AHCT1G126Q is an automotive compliant, single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a LOW-level is applied to the output enable (OE) pin. The device is designed for operation with a power supply range of 4.5V to 5.5V.

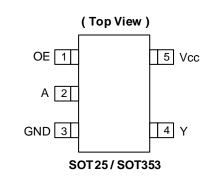
### **Pin Assignments**

Applications

General Purpose Logic

Range

Wide Array of Products, such as:



Automotive Applications within Grade 1 Temperature

Industrial Computing/Controls/Automation

Industrial/Agricultural Equipment

High Reliability Networking/Communications

## Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 5.0V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHCT1G126Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### Notes:

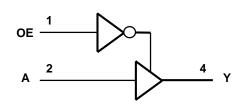
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



### **Pin Descriptions**

Pin Name	Description
OE	Output Enable Active HIGH
А	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

## Logic Diagram



## **Function Table**

Inp	Output	
OE	А	Y
Н	Н	н
н	L	L
L	Х	Z

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
Vi	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
I <sub>IK</sub>	Input Clamp Current VI < 0	-20	mA
IOK	Output Clamp Current ( $V_O < 0$ or $V_O > V_{CC}$ )	±20	mA
lo	Continuous Output Current ( $V_0 = 0$ to $V_{CC}$ )	±25	mA
Icc	Continuous Current Through V <sub>CC</sub>	75	mA
I <sub>GND</sub>	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
TSTG	Storage Temperature	-65 to +150	°C
Pp	Total Power Dissipation (Note 6)	250	mW

# PD Total Power Dissipation (Note 6) 250 r Notes: 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation sh

4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T<sub>J</sub>. Refer to package thermal characteristics section.



## Recommended Operating Conditions (Note 7)

Symbol	Pa	rameter	Min	Max	Unit
Vcc	Operating Voltage	—	4.5	5.5	V
VIH	High-Level Input Voltage	$V_{CC} = 5V \pm 0.5V$	2.0	_	V
VIL	Low-Level Input Voltage	$V_{CC} = 5V \pm 0.5V$	—	0.8	V
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Іон	High-Level Output Current	$V_{CC} = 5V \pm 0.5V$	—	-8	mA
Iol	Low-Level Output Current	$V_{CC} = 5V \pm 0.5V$	_	8	mA
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 5V \pm 0.5V$	_	20	ns/V
TA	Ambient Temperature	_	-40	+125	°C

Note: 7. Unused inputs should be held at  $V_{CC}$  or Ground.

## Electrical Characteristics (All typical values are at V<sub>CC</sub> = 3.3V, T<sub>A</sub> = +25°C.)

		<b>T</b> ( <b>D</b> )   ()			+25°C		-40°C to	o +85°C	-40°C to	+125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
	High Level Output	$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$	4.5V	4.4	4.5		4.4	_	4.4		V
V <sub>OH</sub>	Voltage	$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -8mA$	4.5V	3.94	_	_	3.8	_	3.70		V
	Low Level Output	VI = VIH or VIL I <sub>OL</sub> = 50µA	4.5V		0	0.1		0.1	_	0.1	V
VOL	V <sub>OL</sub> Voltage	$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 8mA$	4.5V		_	0.36	1	0.44	_	0.55	V
loz	Z State Leakage Current	$V_1 = 5.5V$ or GND $V_0 = 0$ to 5.5V	5.5V		_	0.25		2.5	_	10	μA
lı –	Input Current	V <sub>I</sub> = 5.5V or GND	0 to 5.5V	Ι	_	±0.1	_	±1	_	±2	μA
∆lcc	Additional Supply Current	Per input pin; $V_I = 3.4V$ ; other inputs at $V_{CC}$ or GND; $I_O = 0$	5.5V		_	1.35	_	1.5	_	1.5	mA
Icc	Supply Current	$V_I = 5.5V \text{ or GND}$ $I_O = 0$	5.5V	_	_	1	_	10	_	40	μA
CI	Input Capacitance	$V_I = V_{CC}$ or GND	5.5V	_	1.5	10	_	10	_	10	рF



## **Package Characteristics**

Symbol	Parameter	Package	Test Conditions	Min	Тур	Мах	Unit
0	Thermal Resistance	SOT25	Note 0		184	_	00000
θја	Junction-to-Ambient	SOT353	Note 8		385	—	°C/W
0	Thermal Resistance	SOT25		_	62	_	
θις	Junction-to-Case	SOT353	Note 8	_	164	_	°C/W

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

## **Switching Characteristics**

Doromotor	From	То	Test		+25°C		-40°C t	o +85°C	-40°C to	o +125°C	Unit
Parameter	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	< Unit
	^	V	C∟= 15pF	1.0	3.4	5.5	1.0	6.5	1.0	7.0	ns
tpd	A Y	C <sub>L</sub> = 50pF	1.0	4.8	7.5	1.0	8.5	1.0	9.5	ns	
	05	Ň	$C_L = 15 pF$	1.0	3.9	5.1	1.0	6.0	1.0	6.5	ns
ten	OE	Ŷ	$C_L = 50 pF$	1.0	5.1	7.5	1.0	9.0	1.0	9.5	ns
	05	V	C <sub>L</sub> = 15pF	1.0	4.5	6.8	1.0	8.0	1.0	8.5	ns
tDIS	OE	Ŷ	C <sub>L</sub> = 50pF	1.0	6.1	8.8	1.0	10.0	1.0	11.0	ns

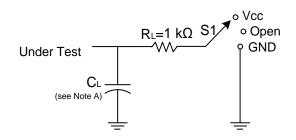
## **Operating Characteristics**

 $T_A = +25^{\circ}C$ 

	Parameter	Test Conditions	Тур	Unit
CPD	Power Dissipation Capacitance	$V_{CC} = 5.0V, f = 1MHz$ $C_L = 50pF$ $V_I = GND to V_{CC}$	11	pF



## **Measurement Information**

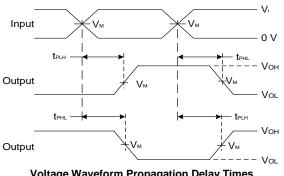


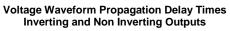
Test	\$1
tplh/tphl	Open
tplz/tpzl	Vload
tpHz/tpzH	GND

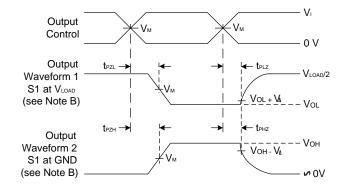
	Inputs		Mar	N.	•		
Vcc	Vi	tr/tr	∨м	VLOAD	C∟	R∟	VΔ
5V±0.5V	GND to 3V	≤2.5ns	1.5V	Vcc	15pF	1kΩ	0.3V
5V±0.5V	GND to 3V	≤2.5ns	1.5V	Vcc	50pF	1kΩ	0.3V



**Voltage Waveform Pulse Duration** 







Voltage Waveform Enable and Disable Times Low and High Level Enabling

#### Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 1MHz.

C. Inputs are measured separately one transition per measurement.

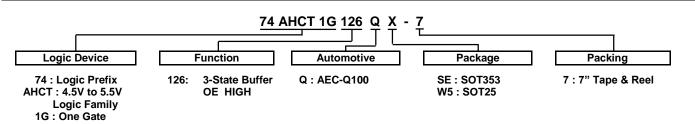
D. tPLZ and tPHZ are the same as tDIS.

E.  $t_{\text{PZL}}$  and  $t_{\text{PZH}}$  are the same as  $t_{\text{EN.}}$ 

F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



### Ordering Information (Note 9)

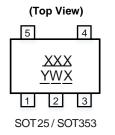


Part Number	Package	Package	Package Size	7" Tape and Reel		
Fait Number	Code	(Notes 10 & 11)	Fackage Size	Quantity	Part Number Suffix	
74AHCT1G126QSE-7	SE	SOT353	$2.15$ mm $\times 2.1$ mm $\times 1.1$ mm 0.65mm lead pitch	3000/Tape & Reel	-7	
74AHCT1G126QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000/Tape & Reel	-7	

Notes: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html. 11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

## **Marking Information**



$\underline{XXX}$ : Identification Code $\underline{Y}$ : Year 0~9
W : Week: A~Z 1~26 week
a~z 27~52 week z represents week 52 and 53
X : A~ Z: Internal Code

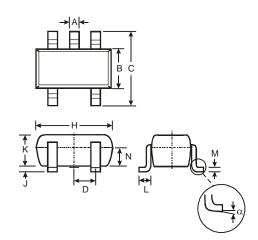
Part Number	Package	Identification Code
74AHCT1G126QW5-7	SOT25	ZZQ
74AHCT1G126QSE-7	SOT353	ZZQ



## **Package Outline Dimensions**

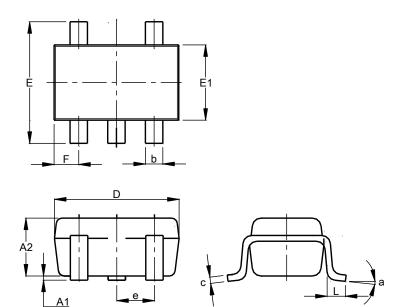
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



SOT25					
Dim					
חווס			Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D	-	-	0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
κ	1.00	1.30	1.10		
L	0.35	0.55	0.40		
М	0.10	0.20	0.15		
Ν	0.70	0.80	0.75		
α	0°	8°	-		
All Dimensions in mm					

#### (2) Package Type: SOT353



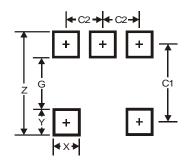
SOT353				
Dim	Min	Max	Тур	
A1	0.00	0.10	0.05	
A2	0.90	1.00	0.95	
b	0.10	0.30	0.25	
Ċ	0.10	0.22	0.11	
D	1.80	2.20	2.15	
Е	2.00	2.20	2.10	
E1	1.15	1.35	1.30	
e	0.650 BSC			
F	0.40	0.45	0.425	
L	0.25	0.40	0.30	
а	0°	8°		
All Dimensions in mm				



## **Suggested Pad Layout**

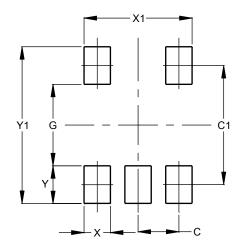
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

#### (2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Ŷ	0.600
Y1	2.500

### **Mechanical Data**

#### SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.0158 grams (Approximate)

#### SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0064 grams (Approximate)



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